

3-TO-8 LINE DECODER/DEMULTIPLEXER; INVERTING

FEATURES

- Demultiplexing capability
- Multiple input enable for easy expansion
- Ideal for memory chip select decoding
- Active LOW mutually exclusive outputs
- Output capability: standard
- ICC category: MSI

GENERAL DESCRIPTION

The 74HC/HCT138 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT138 decoders accept three binary weighted address inputs (A₀, A₁, A₂) and when enabled, provide 8 mutually exclusive active LOW outputs (\bar{Y}_0 to \bar{Y}_7).

The "138" features three enable inputs: two active LOW (\bar{E}_1 and \bar{E}_2) and one active HIGH (E₃). Every output will be HIGH unless \bar{E}_1 and \bar{E}_2 are LOW and E₃ is HIGH.

This multiple enable function allows easy parallel expansion of the "138" to a 1-of-32 (5 lines to 32 lines) decoder with just four "138" ICs and one inverter.

The "138" can be used as an eight output demultiplexer by using one of the active LOW enable inputs as the data input and the remaining enable inputs as strobes. Unused enable inputs must be permanently tied to their appropriate active HIGH or LOW state.

The "138" is identical to the "238" but has inverting outputs.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t _{PHL} / t _{PLH}	propagation delay A _n to \bar{Y}_n	C _L = 15 pF V _{CC} = 5 V	12	17	ns
t _{PHL} / t _{PLH}	E ₃ to \bar{Y}_n E _n to \bar{Y}_n		14	19	ns
C _I	input capacitance		3.5	3.5	pF
C _{PD}	power dissipation capacitance per package	notes 1 and 2	67	67	pF

GND = 0 V; T_{amb} = 25 °C; t_r = t_f = 6 ns

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz C_L = output load capacitance in pF
 f_o = output frequency in MHz V_{CC} = supply voltage in V
 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs

2. For HC the condition is V_I = GND to V_{CC}
 For HCT the condition is V_I = GND to V_{CC} - 1.5 V

PACKAGE OUTLINES

SEE PACKAGE INFORMATION SECTION

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 2, 3	A ₀ to A ₂	address inputs
4, 5	\bar{E}_1, \bar{E}_2	enable inputs (active LOW)
6	E ₃	enable input (active HIGH)
8	GND	ground (0 V)
15, 14, 13, 12, 11, 10, 9, 7	\bar{Y}_0 to \bar{Y}_7	outputs (active LOW)
16	V _{CC}	positive supply voltage

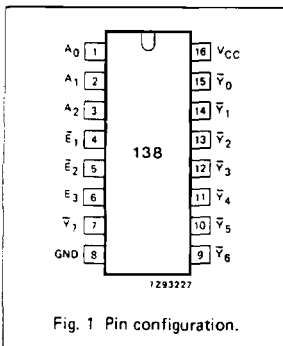


Fig. 1 Pin configuration.

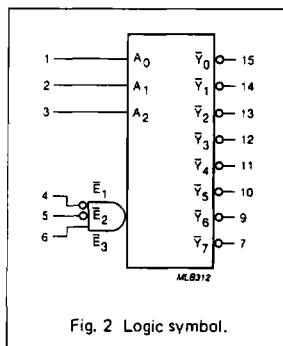


Fig. 2 Logic symbol.

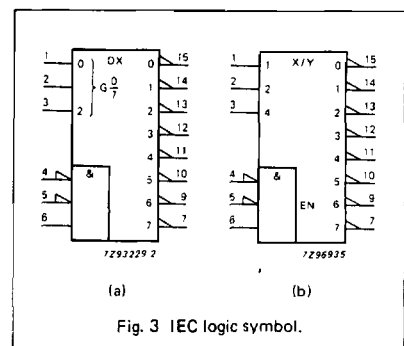
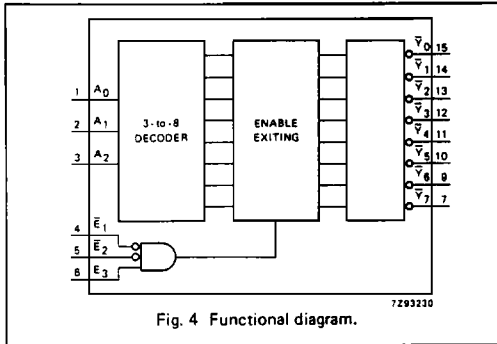


Fig. 3 IEC logic symbol.

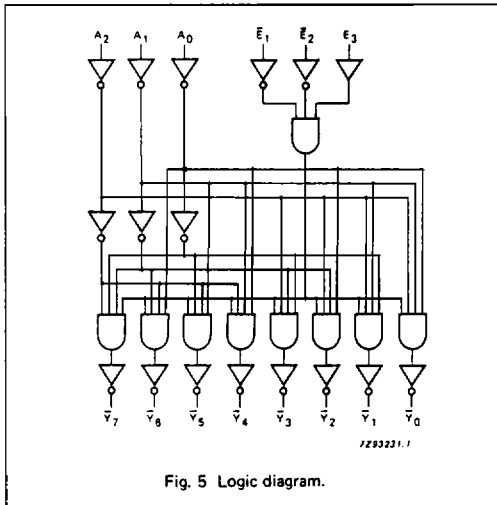
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FUNCTION TABLE

INPUTS						OUTPUTS							
\bar{E}_1	\bar{E}_2	E_3	A_0	A_1	A_2	\bar{Y}_0	\bar{Y}_1	\bar{Y}_2	\bar{Y}_3	\bar{Y}_4	\bar{Y}_5	\bar{Y}_6	\bar{Y}_7
H	X	X	X	X	X	H	H	H	H	H	H	H	H
X	H	X	X	X	X	H	H	H	H	H	H	H	H
X	X	L	X	X	X	H	H	H	H	H	H	H	H
L	L	H	L	L	L	L	H	H	H	H	H	H	H
L	L	H	H	L	L	L	H	L	H	H	H	H	H
L	L	H	L	H	L	L	H	H	L	H	H	H	H
L	L	H	H	H	L	L	H	H	H	L	H	H	H
L	L	H	L	L	H	H	H	H	H	L	H	H	H
L	L	H	L	H	H	H	H	H	H	H	L	H	H
L	L	H	H	L	H	H	H	H	H	H	H	L	H
L	L	H	H	H	H	H	H	H	H	H	H	H	L

H = HIGH voltage level
L = LOW voltage level
X = don't care



DC CHARACTERISTICS FOR 74HC

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: standard

 I_{CC} category: MSI

AC CHARACTERISTICS FOR 74HC

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

SYMBOL	PARAMETER	T_{amb} (°C)						UNIT	TEST CONDITIONS		
		74HC							V_{CC} V	WAVEFORMS	
		+25			-40 to +85		-40 to +125				
		min.	typ.	max.	min.	max.	min.				max.
t_{PHL}/t_{PLH}	propagation delay A_n to \bar{Y}_n		41 15 12	150 30 26		190 38 33		225 45 38	ns	2.0 4.5 6.0	Fig. 6
t_{PHL}/t_{PLH}	propagation delay E_3 to \bar{Y}_n		47 17 14	150 30 26		190 38 33		225 45 38	ns	2.0 4.5 6.0	Fig. 6
t_{PHL}/t_{PLH}	propagation delay E_n to \bar{Y}_n		47 17 14	150 30 26		190 38 33		225 45 38	ns	2.0 4.5 6.0	Fig. 7
t_{THL}/t_{TLH}	output transition time		19 7 6	75 15 13		95 19 16		110 22 19	ns	2.0 4.5 6.0	Figs 6 and 7

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DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: standard

I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications. To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
A _n	1.50
E _n	1.25
E ₃	1.00

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T _{amb} (°C)						UNIT	TEST CONDITIONS		
		74HCT							V _{CC} V	WAVEFORMS	
		+25			-40 to +85		-40 to +125				
		min.	typ.	max.	min.	max.	min.				max.
t _{PHL} / t _{PLH}	propagation delay A _n to \bar{Y}_n		20	35		44		53	ns	4.5	Fig. 6
t _{PHL} / t _{PLH}	propagation delay E ₃ to \bar{Y}_n		18	40		50		60	ns	4.5	Fig. 6
t _{PHL} / t _{PLH}	propagation delay E _n to \bar{Y}_n		19	40		50		60	ns	4.5	Fig. 7
t _{THL} / t _{TLH}	output transition time		7	15		19		22	ns	4.5	Figs 6 and 7

AC WAVEFORMS

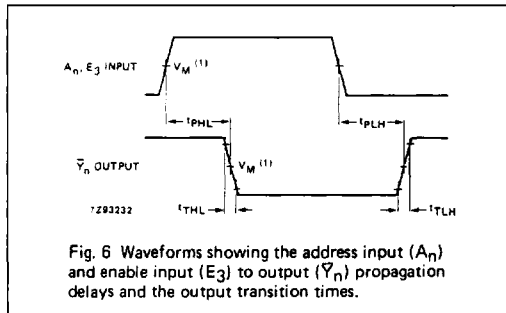


Fig. 6 Waveforms showing the address input (A_n) and enable input (E_3) to output (\bar{Y}_n) propagation delays and the output transition times.

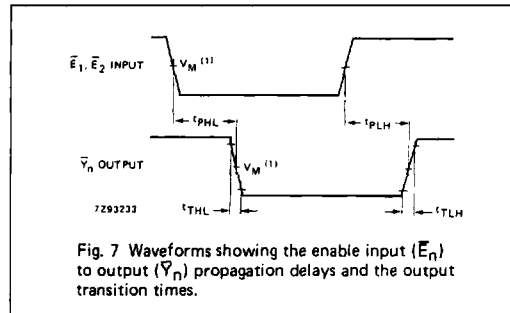


Fig. 7 Waveforms showing the enable input (\bar{E}_n) to output (\bar{Y}_n) propagation delays and the output transition times.

Note to AC waveforms

- (1) HC : $V_M = 50\%$; $V_I = \text{GND to } V_{CC}$.
HCT: $V_M = 1.3 \text{ V}$; $V_I = \text{GND to } 3 \text{ V}$.